

SANYO Semiconductors DATA SHEET

2SK4227JS — General-Purpose Switching Device

Applications

Features

- · Low ON-resistance.
- · Motor drive.
- · Avalanche resistance guarantee.
- · 10V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		75	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		48	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	192	А
Allowable Power Dissipation	D-		2.0	W
	PD	Tc=25°C	35	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		100	mJ
Avalanche Current *2	lav		48	А

Note :*1 V_{DD}=30V, L=50 μ H, I_{AV}=48A *2 L≤50 μ H, Single pulse

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	UIIIL
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	75			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =75V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ

Marking: K4227 Continued on next page.

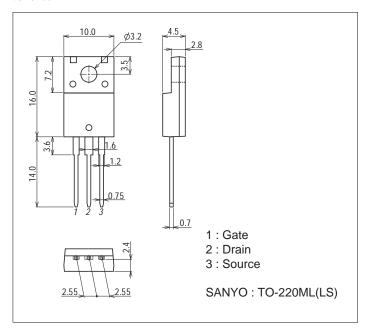
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Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			1.1
		Conditions	min	typ	max	Unit
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2		4	V
Forward Transfer Admittance	yfs	VDS=10V, ID=24A	21	35		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=24A, VGS=10V		10.5	13.7	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		5400		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		480		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		350		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		61		ns
Rise Time	t _r	See specified Test Circuit.		220		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		240		ns
Fall Time	tf	See specified Test Circuit.		150		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =48A		100		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =48A		30		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =48A		28		nC
Diode Forward Voltage	V _{SD}	I _S =48A, V _{GS} =0V		0.9	1.2	V

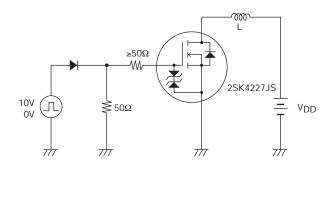
Package Dimensions

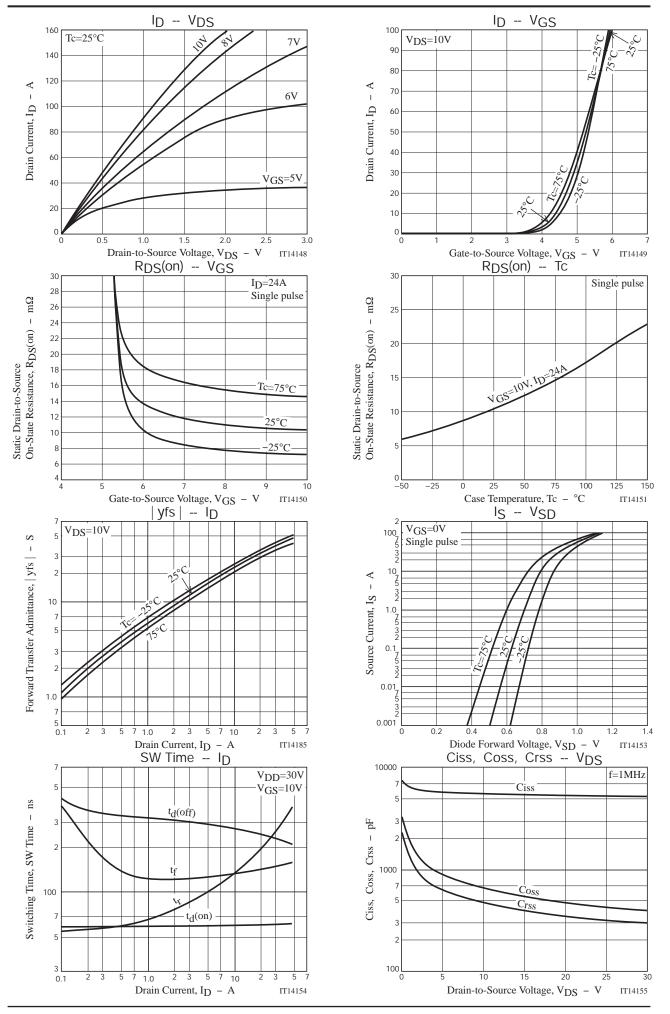
unit : mm (typ) 7525-002

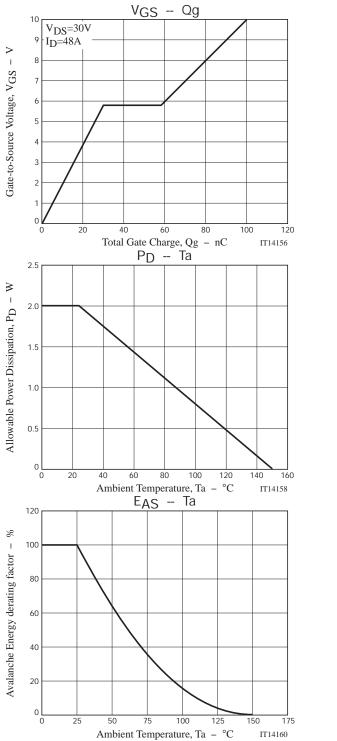


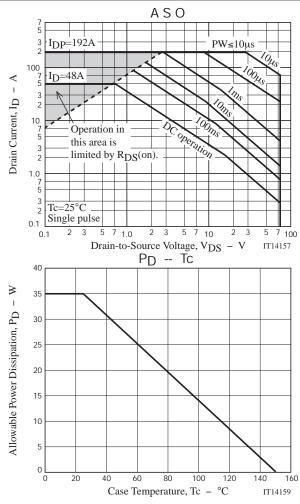
Switching Time Test Circuit

Avalanche Resistance Test Circuit









Note on usage : Since the 2SK4227JS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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